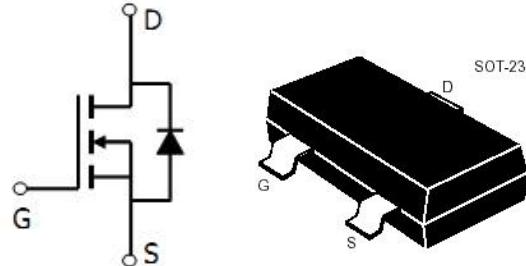


GM2302

SOT-23 場效應晶體管(SOT-23 Field Effect Transistors)



N-Channel Enhancement-Mode MOS FETs

N 溝道增強型 MOS 場效應管

■MAXIMUM RATINGS 最大額定值

| Characteristic 特性參數 | Symbol 符號 | Rat 額定值 | Unit 單位 |
|---|--------------|-------------|--------------------|
| Drain-Source Voltage 漏極-源極電壓 | BV_{DSS} | 20 | V |
| Gate- Source Voltage 柵極-源極電壓 | V_{GS} | ± 10 | V |
| Drain Current (continuous) 漏極電流 - 連續 | I_D | 3.5 | A |
| Drain Current (pulsed) 漏極電流 - 脉冲 | I_{DM} | 11 | A |
| Total Device Dissipation 總耗散功率 $TA=25^{\circ}\text{C}$ 環境溫度為 25°C | P_D | 1000 | mW |
| Junction 結溫 | T_J | 150 | $^{\circ}\text{C}$ |
| Storage Temperature 儲存溫度 | T_{stg} | -55 to +150 | $^{\circ}\text{C}$ |

■DEVICE MARKING 打標

| |
|-----------|
| GM2302=A2 |
|-----------|

GM2302

■ELECTRICAL CHARACTERISTICS 電特性

($T_A=25^\circ\text{C}$ unless otherwise noted 如無特殊說明，溫度為 25°C)

| Characteristic 特性參數 | Symbol 符號 | Min 最小值 | Typ 典型值 | Max 最大值 | Unit 單位 |
|--|---------------------|------------|------------|------------|------------------|
| Drain-Source Breakdown Voltage 漏極-源極擊穿電壓($I_D = 250\mu\text{A}, V_{GS}=0\text{V}$) | BV_{DSS} | 20 | — | — | V |
| Gate Threshold Voltage 柵極開啓電壓($I_D = 250\mu\text{A}, V_{GS}= V_{DS}$) | $V_{GS(\text{th})}$ | 0.5 | — | 1.5 | V |
| Diode Forward Voltage Drop 內附二極管正向壓降($I_S = 0.75\text{A}, V_{GS}=0\text{V}$) | V_{SD} | — | — | 1.5 | V |
| Zero Gate Voltage Drain Current 零柵壓漏極電流($V_{GS}=0\text{V}, V_{DS}= 16\text{V}$) ($V_{GS}=0\text{V}, V_{DS}= 16\text{V}, T_A=55^\circ\text{C}$) | I_{DSS} | — | — | 1 10 | μA |
| Gate Body Leakage 柵極漏電流($V_{GS}=\pm 10\text{V}, V_{DS}=0\text{V}$) | I_{GSS} | — | — | ± 100 | nA |
| Static Drain-Source On-State Resistance 静态漏源導通電阻($I_D=2.8\text{A}, V_{GS}=4.5\text{V}$) ($I_D=2\text{A}, V_{GS}=2.5\text{V}$) | $R_{DS(\text{ON})}$ | — | — | 60 80 | $\text{m}\Omega$ |
| Input Capacitance 輸入電容 ($V_{GS}=0\text{V}, V_{DS}= 10\text{V}, f=1\text{MHz}$) | C_{ISS} | — | — | 800 | pF |
| Common Source Output Capacitance 共源輸出電容($V_{GS}=0\text{V}, V_{DS}= 10\text{V}, f=1\text{MHz}$) | C_{OSS} | — | — | 200 | pF |
| Turn-ON Time 开啓時間 ($V_{DS}= 10\text{V}, I_D= 3.5\text{A}, R_{GEN}=10\Omega$) | $t_{(\text{on})}$ | — | — | 20 | ns |
| Turn-OFF Time 焦斷時間 ($V_{DS}= 10\text{V}, I_D= 3.5\text{A}, R_{GEN}=10\Omega$) | $t_{(\text{off})}$ | — | — | 80 | ns |

Pulse Width $\leq 300 \mu\text{s}$; Duty Cycle $\leq 2.0\%$